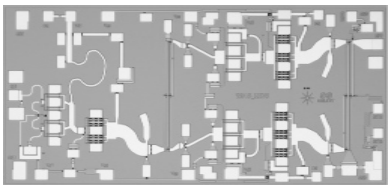
AMMC-5033
17.7 - 32 GHz Power Amplifier

Data Sheet



Chip Size: 2730 x 1300 µm (108 x 51.6 mils)
Chip Size Tolerance: ± 10 µm (±0.4 mils)
Chip Thickness: 100 ± 10 µm (4 ± 0.4 mils)
Pad Dimensions: 80 x 80 µm (2.95 ± 0.4 mils)

Description

Avago's AMMC-5033 is a MMIC power amplifier designed for use in wireless transmitters that operate within 17.7 GHz to 32 GHz range. At 25 GHz, it provides 27 dBm of output power (P-1dB) and 20 dB of small- signal gain from a small easy-to-use device. The device has input and output matching circuitry for use in 50 Ω environments. The AMMC- 5033 also integrates a temperature compensated RF power detection circuit that enables power detection of 0.1 V/W at 22 GHz. For improved reliability and moisture protection, the die is passivated at the active areas.

AMMC-5033 Absolute Maximum Ratings[1]

Symbol	Parameters/Conditions	Units	Min.	Max.
$V_{d1,2}$	Positive Drain Voltage	V		7
V_{g1}, V_{gg}	Gate Supply Voltage	V	-3	0.5
Det Bias	Applied Detector Bias (Optional)	V		7
I_{d1}	First Stage Drain Current	mA		320
I_{d2}	Second Stage Drain Current	mA		640
P_{in}	CW Input Power	dBm		23
T_{ch}	Operating Channel Temp.	°C		+150
T_{stg}	Storage Case Temp.	°C	-65	+150
T_{max}	Maximum Assembly Temp. (60 sec max)	°C		+300

Note:

1. Operation in excess of any one of these conditions may result in permanent damage to this device.

Features

- Wide frequency range: 17.7 – 32 GHz
- High power: P-1dB @ 25 GHz = 27 dBm
- High gain: 20 dB
- Return loss: Input: -13 dB, Output: –20 dB
- Integrated RF power detector

Applications

- Designed for use in transmitters that operate in various frequency bands between 17.7 GHz and 32 GHz.
- Can be driven by the AMMC-5040 (20-40 GHz) or the AMMC-5618 (6-20 GHz) MMIC amplifiers, increasing the power handling capability of transmitters requiring linear operation.

Note: These devices are ESD sensitive. The following precautions are strongly recommended:
Ensure that an ESD approved carrier is used when dice are transported from one destination to another.
Personal grounding is to be worn at all times when handling these devices.

AMMC-5033 DC Specifications/Physical Properties[1]

Symbol	Parameters and Test Conditions	Units	Min.	Typ.	Max.
I_{d1}	First Stage Drain Supply Current (V_{d1} = 3.5 V, V_{g1} = Open, V_{gg} set for I_{d2} Typical)	mA		280	320
I_{d2}	Second Stage Drain Supply Current (V_{d2} = 5 V, V_{g1} = Open, V_{gg} set for I_{d2} Typical)	V		500	
Vgg	Gate Supply Operating Voltage ($I_{d1(Q)} + I_{d2(Q)}$ = 780 (mA))	V	-0.95	-0.6	-0.4
DETBias	Detector Bias Voltage (Optional)	V		Vd2	
$\theta_{c1(ch-bs)}$	First Stage Thermal Resistance[2] (Backside Temperature, Tb = 25°C)	°C/W		31	
$\theta_{c2(ch-bs)}$	Second Stage Thermal Resistance[2, 3] (Backside Temperature, Tb = 25°C)	°C/W		19	

Notes:
1. Backside temperature T_b = 25°C unless otherwise noted.
2. Channel-to-backside Thermal Resistance (θch-b) = 42°C/W at Tchannel (Tc) = 150°C as measured using infrared microscopy. Thermal Resistance at backside temperature (Tb) = 25°C calculated from measured data.

AMMC-5033 RF Specifications[4, 5]

Tb = 25°C, V_{d1} = 3.5 V, V_{d2} = 5 V, $I_{d1(Q)}$ = 280 mA, $I_{d2(Q)}$ = 500 mA, Zo = 50 Ω

			Lower Band Specifications (17.7 - 21 GHz)			Mid Band Specifications (21 - 26.5 GHz)			Upper Band Specifications (26.5 - 32 GHz)		
Symbol	Parameters and Test Condition	Unit	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.
Gain	Small-Signal Gain[5]	dB	20	22		17.5	20		16.5	18.5	
P_{-1dB}	Output Power at 1dB Gain Compression[6]	dB	23.5	25		25.5	27		25	26.5	
P_{-3dB}	Output Power at 3dB Gain Compression[6]	dB		27			28			27	
OIP_3	Output Third Order Intercept Point;[6]; Δf = 2 MHz; Pin = +2 dBm	dBm	27	29		29	32		29	32	
RL_{in}	Input Return Loss[5]	dB	11.5	13.5		11	13		11	13	
RL_{out}	Output Return Loss[5]	dB	14	20		14	19		15	22	
Isolation	Min. Reverse Isolation	dB		47			48			46	

Notes:
4. Data measured in wafer form T_b = 25°C.
5. 100% on-wafer RF test is done at frequency = 17.7, 21, 26.5 and 32 GHz.
6. 100% on-wafer test frequency = 17.7, 26.5 and 32 GHz.

AMMC-5033 Typical Performances

(T_b = 25°C, V_{d1} = 3.5 V, I_{D1} = 280 mA, V_{d2} = 5 V, I_{d2} = 500 mA, Z_{in} = Z_{out} = 50 Ω)

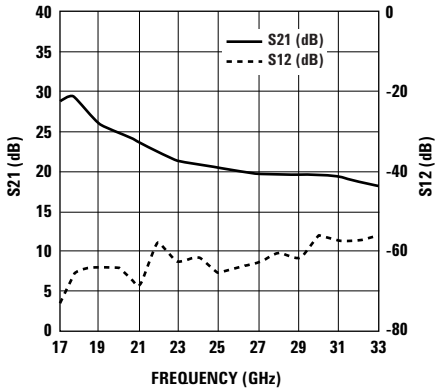


Figure 1. Gain and reverse isolation

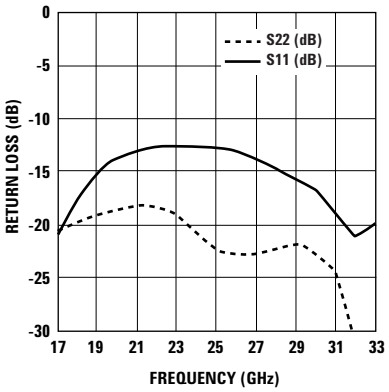


Figure 2. Return loss (input and output)

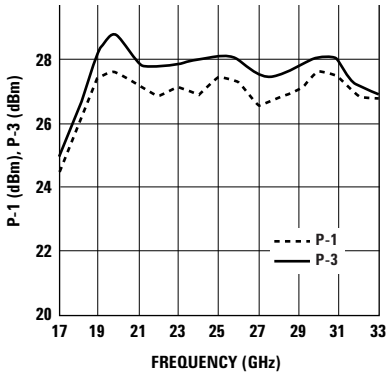


Figure 3. Output power at 1 dB and 3 dB gain compression

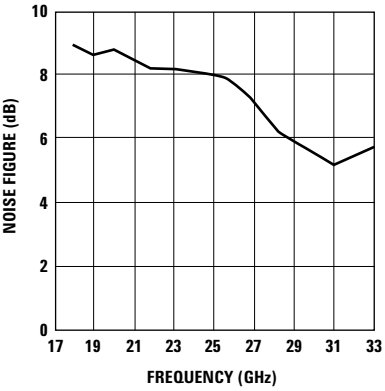


Figure 4. Noise figure

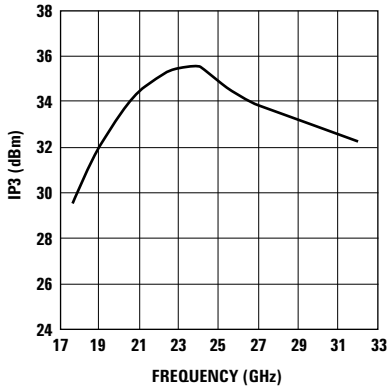


Figure 5. Output 3rd order intercept point

AMMC-5033 Typical Performance Curves (Over Temperature and Voltage)

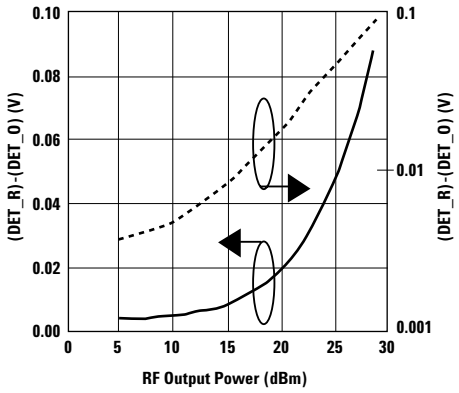


Figure 6. Linear and log detector voltage and output power, freq. = 22 GHz, Det_B = 5 V

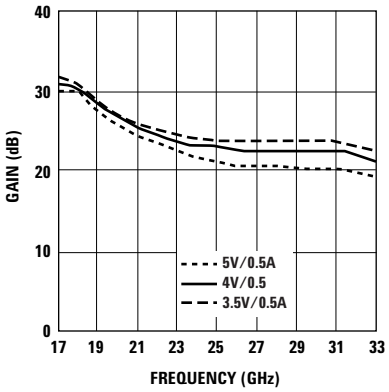


Figure 7. Gain and V_{d2} voltage, V_{d1} = 3.5 V (constant)

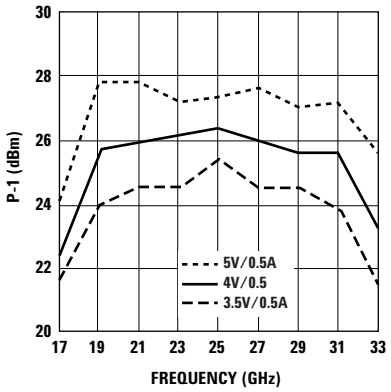


Figure 8. Output power at 1 dB gain compression and V_{d2} voltage, V_{d1} = 3.5 V (constant)

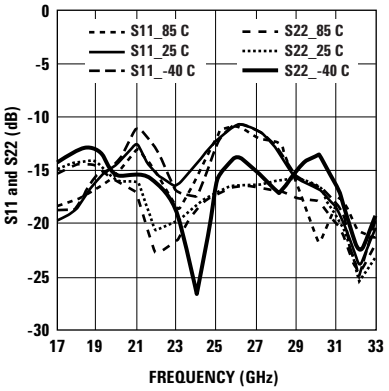


Figure 9. Return-loss with temperature

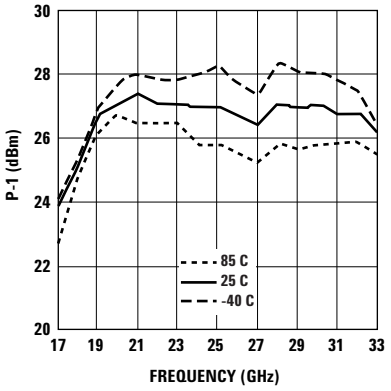


Figure 10. Output power at 1 dB gain compression and temperature

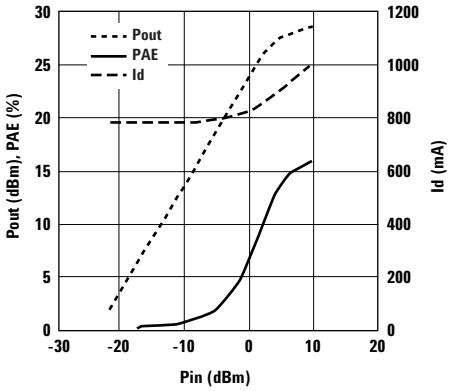


Figure 11. Output power, PAE, and total drain. Current vs. input power at 25 GHz

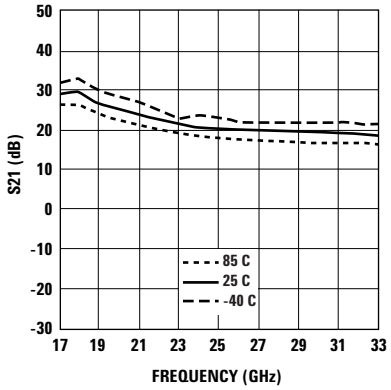


Figure 12. Gain with temperature

Typical Scattering Parameters[1]

(T_b = 25°C, V_{d1} = 3.5 V, I_{D1} = 280 mA, V_{d2} = 5 V, I_{D2} = 500 mA, $Z_{in} = Z_{out}$ = 50 Ω)

Freq	S11			S21			S12			S22		
[GHz]	dB	Mag	Phase	dB	Mag	Phase	dB	Mag	Phase	dB	Mag	Phase
1	-10.7	0.29	173	-51.1	0.003	-163	-95.1	1.77E-05	128	-0.5	0.95	-26
2	-11.0	0.28	167	-70.1	0	79	-83.1	6.97E-05	76	-0.7	0.92	-51
3	-11.4	0.27	161	-46.6	0.005	-103	-74.5	1.89E-04	81	-1.2	0.87	-76
4	-12.1	0.25	153	-37.3	0.014	72	-74.5	1.88E-04	69	-2.2	0.78	-95
5	-15.3	0.17	140	-22.6	0.074	-31	-80.3	9.66E-05	-47	-2.4	0.76	-112
6	-12.2	0.25	149	-20.4	0.096	144	-80.1	9.90E-05	-126	-2.8	0.73	-130
7	-14.0	0.2	143	-20.5	0.095	79	-80.3	9.68E-05	94	-4.0	0.63	-146
8	-15.3	0.17	139	-25.4	0.053	-3	-74.1	1.97E-04	35	-4.2	0.62	-150
9	-17.6	0.13	138	-33.1	0.022	108	-81.4	8.52E-05	-62	-3.5	0.67	-166
10	-19.4	0.11	145	-18.9	0.113	54	-81.4	8.56E-05	-162	-3.8	0.64	177
11	-18.6	0.12	152	-18.2	0.123	-37	-81.3	8.59E-05	151	-4.4	0.6	161
12	-19.7	0.1	141	-29.0	0.035	-77	-74.6	1.86E-04	178	-5.2	0.55	146
13	-24.5	0.06	134	-15.4	0.169	103	-81.3	8.65E-05	-180	-6.3	0.48	131
14	-27.4	0.04	159	0.9	1.107	61	-81.2	8.70E-05	-20	-7.9	0.41	115
15	-30.6	0.03	-148	12.7	4.316	-8	-74.6	1.86E-04	152	-10.1	0.31	100
16	-24.1	0.06	-121	22.6	13.52	-87	-76.2	1.55E-04	144	-13.3	0.22	86
17	-21.2	0.09	-116	28.8	27.62	174	-74.7	1.84E-04	-164	-20.5	0.09	76
18	-18.0	0.13	-116	28.7	27.25	73	-64.8	5.75E-04	165	-20.0	0.1	133
19	-15.5	0.17	-123	26.4	20.92	3	-64.3	6.08E-04	123	-19.4	0.11	130
20	-14.0	0.2	-133	24.7	17.18	-53	-64.4	6.03E-04	90	-19.1	0.11	135
21	-13.3	0.22	-142	23.4	14.82	-103	-69.7	3.27E-04	76	-18.7	0.12	133
22	-13.0	0.22	-151	22.4	13.2	-151	-58.2	1.23E-03	80	-18.5	0.12	129
23	-12.9	0.23	-157	21.5	11.9	164	-63.3	6.80E-04	92	-19.0	0.11	124
24	-12.9	0.23	-163	20.8	10.97	121	-61.0	8.96E-04	44	-20.7	0.09	119
25	-13.0	0.23	-172	20.3	10.36	79	-66.1	4.97E-04	55	-21.8	0.08	122
26	-13.3	0.22	-178	19.9	9.895	37	-64.3	6.09E-04	53	-22.9	0.07	131
27	-13.9	0.2	174	19.7	9.691	-6	-63.1	7.00E-04	58	-22.9	0.07	135
28	-14.9	0.18	165	19.5	9.457	-49	-60.2	9.75E-04	68	-22.6	0.07	142
29	-15.8	0.16	155	19.4	9.384	-94	-61.9	8.00E-04	38	-22.1	0.08	136
30	-17.0	0.14	140	19.3	9.247	-141	-56.3	1.53E-03	25	-22.4	0.08	125
31	-19.1	0.11	113	19.1	8.972	171	-57.7	1.31E-03	15	-24.9	0.06	117
32	-21.0	0.09	75	18.6	8.519	121	-58.2	1.23E-03	1	-31.9	0.03	126
33	-20.5	0.1	30	18.1	7.989	69	-56.0	1.59E-03	-15	-31.4	0.03	-148
34	-17.0	0.14	-9	17.2	7.281	14	-57.7	1.31E-03	-12	-24.4	0.06	-141
35	-14.9	0.18	-31	16.2	6.44	-43	-59.0	1.12E-03	-36	-20.0	0.1	-145
36	-12.8	0.23	-45	14.6	5.378	-104	-60.8	9.14E-04	-40	-16.2	0.16	-152
37	-10.7	0.29	-58	12.1	4.014	-171	-62.9	7.13E-04	-31	-13.1	0.22	-167
38	-9.8	0.33	-71	7.7	2.42	122	-57.1	1.40E-03	-55	-11.1	0.28	174
39	-9.1	0.35	-77	1.9	1.238	65	-61.0	8.94E-04	-61	-10.1	0.31	154
40	-8.5	0.38	-85	-3.5	0.671	14	-60.9	9.04E-04	-59	-9.8	0.33	134
41	-8.6	0.37	-92	-9.2	0.347	-41	-67.6	4.15E-04	-65	-9.7	0.33	116
42	-8.6	0.37	-92	-16.1	0.157	-90	-59.2	1.09E-03	-82	-10.1	0.31	98
43	-8.0	0.4	-92	-23.2	0.069	-134	-61.0	8.95E-04	-75	-10.6	0.29	80
44	-7.6	0.42	-90	-32.0	0.025	-172	-62.0	7.96E-04	-59	-11.4	0.27	62
45	-6.0	0.5	-87	-31.7	0.026	-148	-64.6	5.91E-04	-123	-12.3	0.24	41
46	-4.4	0.6	-93	-40.7	0.009	-164	-61.1	8.84E-04	-82	-13.2	0.22	21
47	-3.5	0.67	-98	-46.2	0.005	62	-102.4	7.57E-06	-171	-14.2	0.2	0
48	-2.7	0.74	-102	-58.4	0.001	80	-60.1	9.93E-04	176	-14.8	0.18	-27
49	-1.8	0.81	-111	-46.4	0.005	50	-59.2	1.10E-03	-69	-14.7	0.18	-49
50	-1.7	0.83	-118	-44.2	0.006	113	-61.9	8.00E-04	26	-14.9	0.18	-77

Note:

1. Data obtained from on-wafer measurements.

Biasing and Operation

The recommended quiescent DC bias condition for optimum efficiency, performance, and reliability is V_{d1} = 3.5 volts and V_{d2} = 5 volts with V_{gg} set for $I_{d1} + I_{d2}$ = 780 mA (no connection to V_{g1}). This bias arrangement results in default quiescent drain currents I_{d1} = 280 mA, I_{d2} = 500 mA. A single DC gate supply connected to V_{gg} will bias all gain stages.

If operation with both V_{d1} and V_{d2} at 5 volts is desired, an additional wire bond connection from the V_{g1} pad to V_{gg} external bypass chip capacitor (shorting V_{g1} to V_{gg}) will balance the current in each gain stage. V_{gg} (= V_{g1}) can be adjusted for $I_{d1} + I_{d2}$ = 780 mA. Muting can be accomplished by setting V_{g1} and/or V_{gg} to the pinch-off voltage V_p.

An optional output power detector network is also provided. Detector sensitivity can be adjusted by biasing the diodes with typically 1 to 5 volts applied to the Det- bias terminal. Simply connecting Det-Bias to the V_{d2} supply is a convenient method of biasing this detector network. The differential voltage between the Det-Ref and Det-Out pads can be correlated with the RF power emerging from the RF output port. The detected voltage is given by:

$$V = (V_{ref} - V_{det}) - V_{ofs}$$

Where V_{ref} is the voltage at the DET_REF port, V_{det} is a voltage at the DET_OUT port, and V_{ofs} is the zero-input-power offset voltage. There are three methods to calculate V_{ofs}:

1. V_{ofs} can be measured before each detector measurement (by removing or switching off the power source and measuring $V_{ref} - V_{det}$). This method gives an error due to temperature drift of less than 0.0002 dB/°C.
2. V_{ofs} can be measured at a single reference temperature. The drift error will be less than 0.25 dB.
3. V_{ofs} can either be characterized over temperature and stored in a lookup table, or it can be measured at two temperatures and a linear fit used to calculate V_{ofs} at any temperature. This method gives an error close to method #1.

With reference to Figure 13, the RF input is DC coupled to a shunt 50 Ω resistor but it is DC blocked to the input of the first stage. The RF output is DC blocked to the output of the second stage, however, it is DC coupled to the detector bias circuit. If the output detector is biased using the on-chip optional Det-Bias network, an external DC blocking capacitor may be required at the RF Output port.

No ground wires are needed since ground connections are made with plated through-holes to the backside of the device.

Assembly Techniques

The backside of the AMMC- 5033 chip is RF ground. For microstripline applications, the chip should be attached directly to the ground plane (e.g., circuit carrier or heatsink) using electrically conductive epoxy.[1,2]

For best performance, the topside of the MMIC should be brought up to the same height as the circuit surrounding it. This can be accomplished by mounting a gold plated metal shim (same length and width as the MMIC) under the chip, which is of the correct thickness to make the chip and adjacent circuit coplanar.

The amount of epoxy used for chip and or shim attachment should be just enough to provide a thin fillet around the bottom perimeter of the chip or shim. The ground plane should be free of any residue that may jeopardize electrical or mechanical attachment.

The location of the RF bond pads is shown in Figure 14. Note that all the RF input and output ports are in a Ground-Signal-Ground configuration.

RF connections should be kept as short as reasonable to minimize performance degradation due to undesirable series inductance. A single bond wire is sufficient for signal connections, however double-bonding with 0.7 mil gold wire or the use of gold mesh is recommended for best performance, especially near the high end of the frequency range.

Thermosonic wedge bonding is the preferred method for wire attachment to the bond pads. Gold mesh can be attached using a 2 mil round tracking tool and a tool force of approximately 22 grams with an ultrasonic power of roughly 55 dB for a duration of 76 ± 8 mS. A guided wedge at an ultrasonic power level of 64 dB can be used for the 0.7 mil wire. The recommended wire bond stage temperature is 150±2°C.

Caution should be taken to not exceed the Absolute Maximum Rating for assembly temperature and time.

The chip is 100 µm thick and should be handled with care. This MMIC has exposed air bridges on the top surface and should be handled by the edges or with a custom collet (do not pick up die with vacuum on die center.)

This MMIC is also static sensitive and ESD handling precautions should be taken.

Notes:

1. Ablebond 84-1 LM1 silver epoxy is recommended.
2. Eutectic attach is not recommended and may jeopardize reliability of the device.

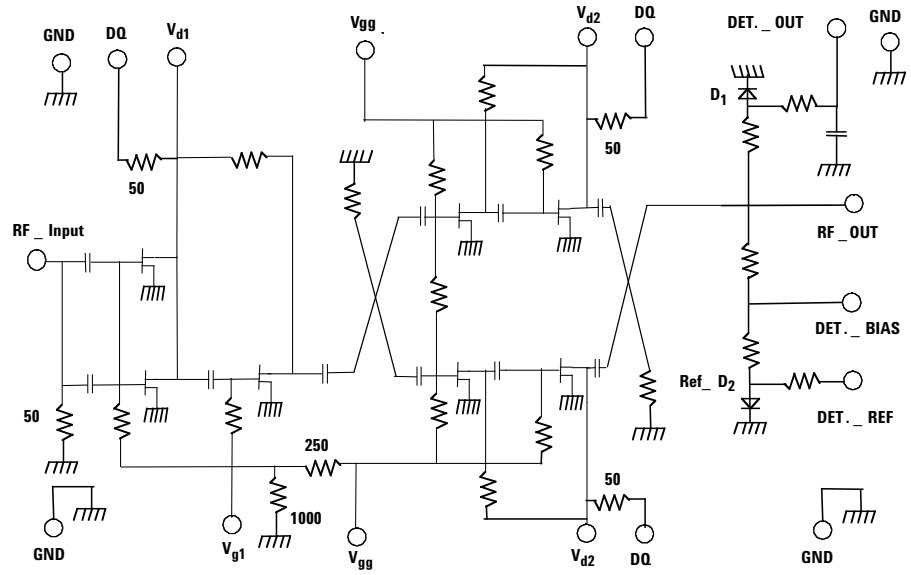


Figure 13. AMMC-5033 schematic

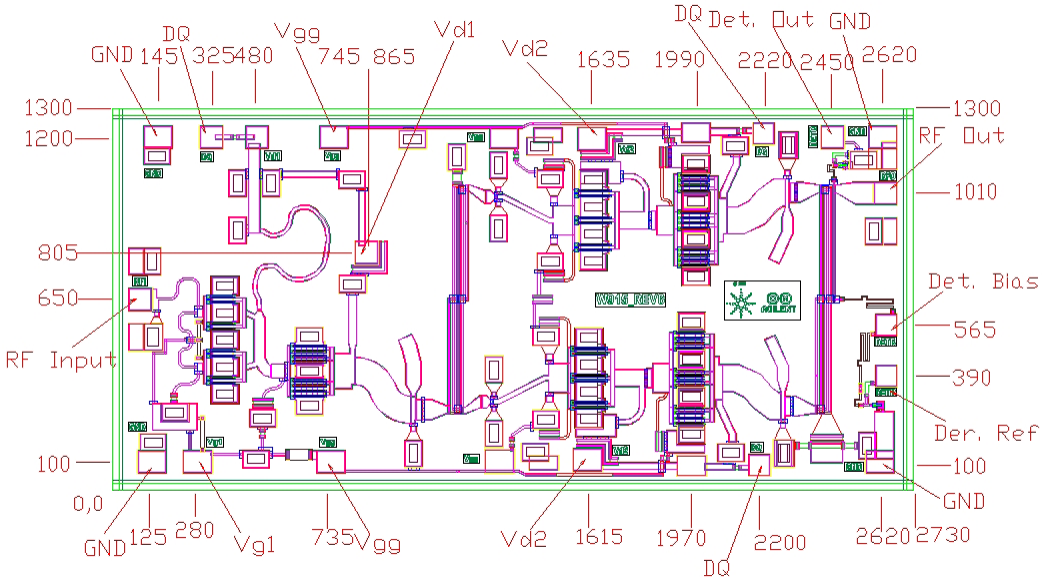


Figure 14. AMMC-5033 bonding pad locations, dimensions are in microns

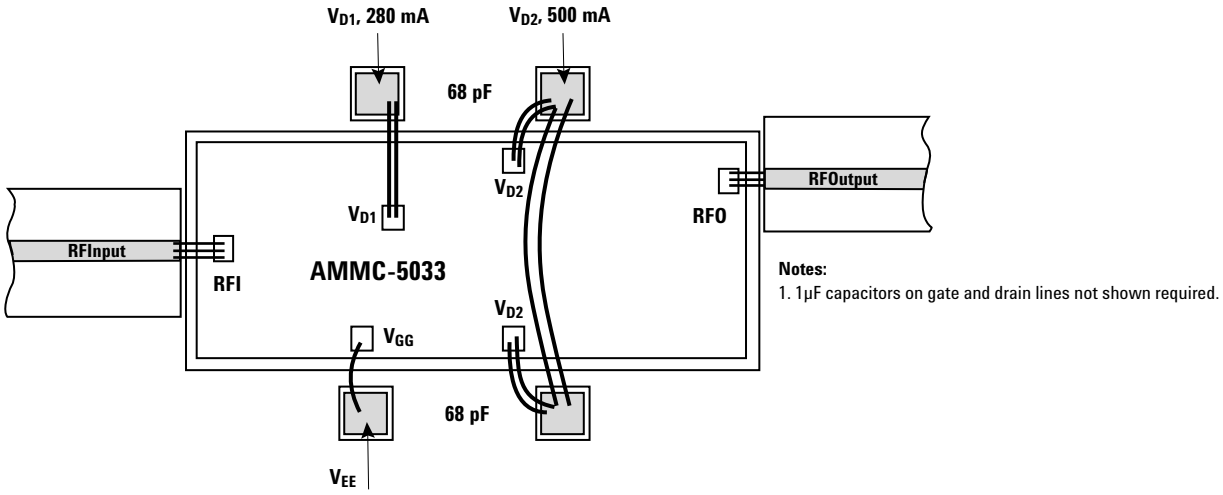


Figure 15. AMMC-5033 assembly diagram

Ordering Information:

AMMC-5033-W10 = 10 devices per tray
AMMC-5033-W50 = 50 devices per tray

For product information and a complete list of distributors, please go to our website: **www.avagotech.com**

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Океан Электроники
Поставка электронных компонентов

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «**JONHON**», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «**FORSTAR**».

AVIC JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).

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